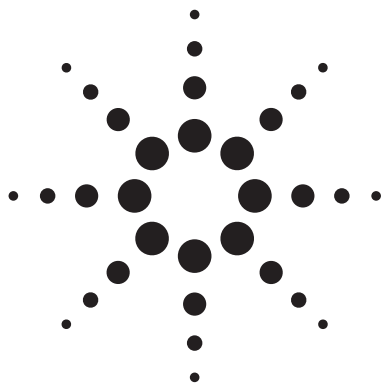




Agilent MSA-0886 Cascadable Silicon Bipolar MMIC Amplifier

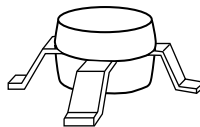
Data Sheet

Description

The MSA-0886 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50 Ω gain block above 0.5 GHz and can be used as a high gain transistor below this frequency. Typical applications include narrow and moderate band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Agilent's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

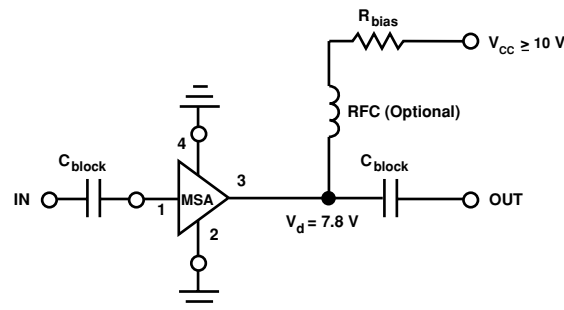
86 Plastic Package



Features

- Lead-free Option Available
- Usable Gain to 5.5 GHz
- High Gain:
32.5 dB Typical at 0.1 GHz
22.5 dB Typical at 1.0 GHz
- Low Noise Figure:
3.3 dB Typical at 1.0 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

Typical Biasing Configuration



Agilent Technologies

MSA-0886 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	65 mA
Power Dissipation ^[2,3]	500 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	–65°C to 150°C

Thermal Resistance^[2]:

$$\theta_{jc} = 140^{\circ}\text{C/W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{\text{CASE}} = 25^{\circ}\text{C}$.
3. Derate at $7.1 \text{ mW/}^{\circ}\text{C}$ for $T_{\text{C}} > 80^{\circ}\text{C}$.

Electrical Specifications^[1], $T_{\text{A}} = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_{\text{d}} = 36 \text{ mA}$, $Z_{\text{o}} = 50 \Omega$	Units	Min.	Typ.	Max.
GP	Power Gain ($ S_{21} ^2$) f = 0.1 GHz f = 1.0 GHz	dB	20.5	32.5 22.5	
VSWR	Input VSWR f = 0.1 to 3.0 GHz			2.1:1	
	Output VSWR f = 0.1 to 3.0 GHz			1.9:1	
NF	50 Ω Noise Figure f = 1.0 GHz	dB		3.3	
P ₁ dB	Output Power at 1 dB Gain Compression f = 1.0 GHz	dBm		12.5	
IP ₃	Third Order Intercept Point f = 1.0 GHz	dBm		27.0	
t _D	Group Delay f = 1.0 GHz	psec		140	
V _d	Device Voltage	V	6.2	7.8	9.4
dV/dT	Device Voltage Temperature Coefficient	mV/°C		–17.0	

Note:

1. The recommended operating current range for this device is 20 to 40 mA. Typical performance as a function of current is on the following page.

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0886-BLK	100	Bulk
MSA-0886-BLKG	100	Bulk
MSA-0886-TR1	1000	7" Reel
MSA-0886-TR1G	1000	7" Reel
MSA-0886-TR2	4000	13" Reel
MSA-0886-TR2G	4000	13" Reel

Note: Order part number with a “G” suffix if lead-free option is desired.

MSA-0886 Typical Scattering Parameters^[1] ($Z_0 = 50\ \Omega$, $T_A = 25^\circ\text{C}$, $I_d = 36\ \text{mA}$)

Freq. GHz	S_{11}		S_{21}			S_{12}			S_{22}		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
0.1	.63	-22	32.5	42.12	160	-36.7	.015	54	.62	-24	0.68
0.2	.56	-41	31.3	36.68	143	-33.9	.020	50	.55	-46	0.64
0.4	.43	-69	28.6	26.94	119	-29.1	.035	52	.43	-79	0.69
0.6	.35	-88	26.4	20.89	104	-27.0	.045	49	.34	-103	0.77
0.8	.30	-104	24.2	16.21	93	-25.3	.054	50	.29	-124	0.83
1.0	.27	-116	22.4	13.20	83	-24.2	.062	49	.26	-139	0.87
1.5	.27	-144	19.2	9.15	65	-21.6	.083	46	.23	-172	0.93
2.0	.31	-166	16.7	6.84	49	-19.5	.105	41	.22	163	0.96
2.5	.35	178	14.8	5.50	38	-17.9	.128	36	.21	149	0.96
3.0	.40	162	12.9	4.41	25	-17.4	.135	30	.20	132	1.01
3.5	.45	149	11.4	3.72	13	-16.8	.145	25	.19	124	1.02
4.0	.51	137	9.9	3.14	1	-16.1	.157	19	.18	121	1.01
5.0	.61	116	7.3	2.31	-22	-15.7	.164	10	.17	130	1.00
6.0	.68	100	4.6	1.69	-42	-15.2	.173	4	.23	143	0.95

Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

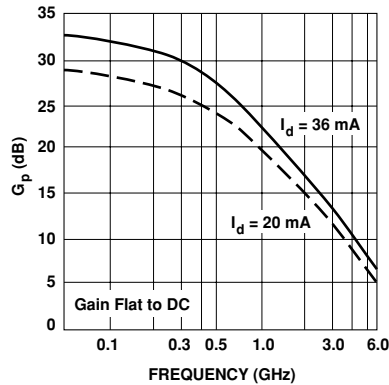


Figure 1. Typical Power Gain vs. Frequency, $I_d = 36\ \text{mA}$.

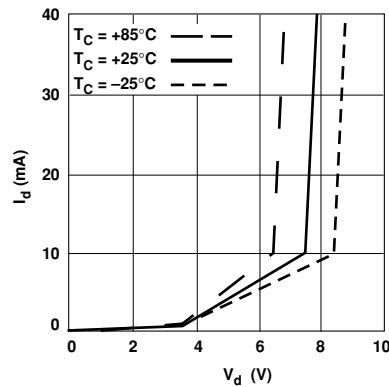


Figure 2. Device Current vs. Voltage.

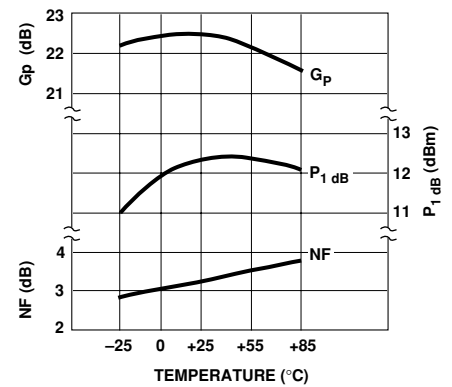


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, $f = 1.0\ \text{GHz}$, $I_d = 36\ \text{mA}$.

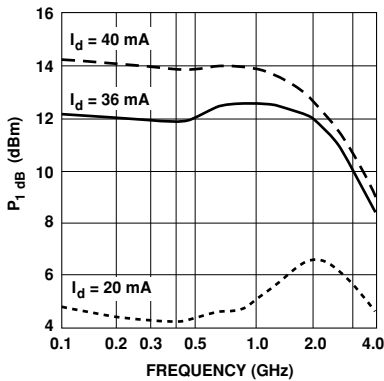


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

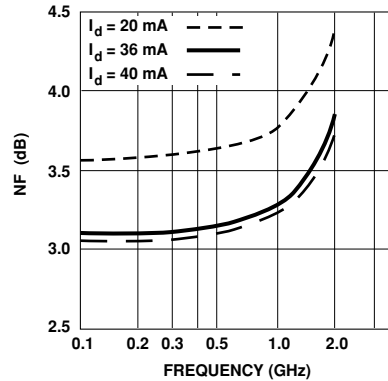
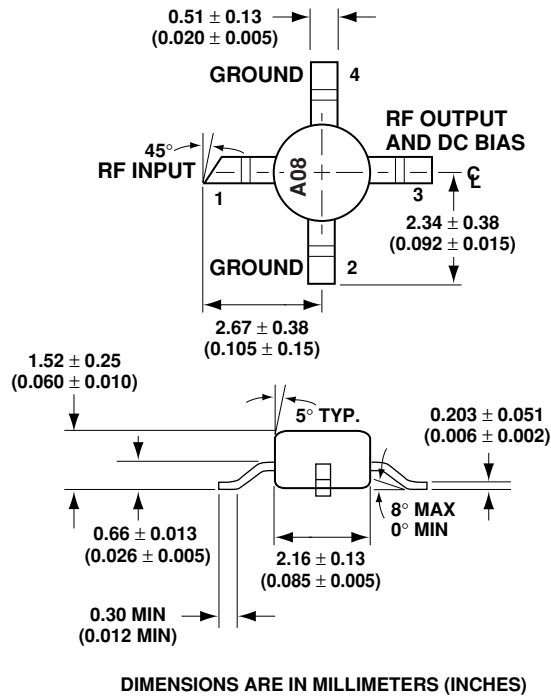


Figure 5. Noise Figure vs. Frequency.

86 Plastic Package Dimensions



www.agilent.com/semiconductors

For product information and a complete list of distributors, please go to our web site.

For technical assistance call:

Americas/Canada: +1 (800) 235-0312 or (916) 788-6763

Europe: +49 (0) 6441 92460

China: 10800 650 0017

Hong Kong: (65) 6756 2394

India, Australia, New Zealand: (65) 6755 1939

Japan: (+81 3) 3335-8152(Domestic/International), or 0120-61-1280(Domestic Only)

Korea: (65) 6755 1989

Singapore, Malaysia, Vietnam, Thailand, Philippines, Indonesia: (65) 6755 2044

Taiwan: (65) 6755 1843

Data subject to change.

Copyright © 2005 Agilent Technologies, Inc.

Obsoletes 5989-2083EN

April 8, 2005

5989-2744EN



Agilent Technologies